Docket No.: M4065.0531/P531 (PATENT)

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Werner Juengling, et al.

Application No.: Not Yet Assigned

Group Art Unit: N/A

Filed: Not Yet Filed

Examiner: Not Yet Assigned

For: A REVERSE METAL PROCESS FOR CREATING A METAL SILICIDE TRANSISTOR GATE STRUCTURE

### POWER OF ATTORNEY BY ASSIGNEE AND CERTIFICATE BY ASSIGNEE UNDER 37 CFR § 3.73(B)

Assistant Commissioner for Patents Washington, DC 20231

Dear Sir:

Micron Technology, Inc., Assignce of the entire right, title and interest in the above-identified application by virtue of an Assignment, a copy which is attached hereto, hereby appoints the attorneys and agents of the firm of Dickstein Shapiro Morin & Oshinsky LLP located at 2101 L Street NW, Washington, DC 20037-1526, listed as follows:

Gary M. Hoffman Thomas J. D'Amico Donald A. Gregory James W. Brady, Jr. Jon D. Grossman Mark J. Thronson Eric Oliver Laurence E. Fisher Ian R. Blum Gabriela I. Coman Ryan H. Flax	26,411 28,371 28,954 32,115 32,699 33,082 35,307 37,131 42,336 50,515 48,141	Richard LaCava John C. Luce Peter McGee Edward A. Meilman Edwin Oh William E. Powell, III Steven S. Rubin Michael J. Scheer Stephen A. Soffen Christopher M. Tanner Ellen S. Tao	41,135 34,378 35,947 24,735 45,319 39,803 43,063 34,425 31,063 41,518 43,383	Gary L. Veron Steven I. Weisburd Mialecka C. Williams Bibbs Peter Zuta Jeremy A. Cubert Gianni Minutoli Michael Bergman Salvatore P. Tamburo Peter A. Veytaman Christopher S. Chow	39,057 27,409 48,037 48,196 40,399 41,198 42,318 45,153 45,920 46,493

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and also, listed as follows:

Keyin D. Martin 38,086 Charles B. Brantley, III

David J. Paul 37,882

Michael L. Lynch

30,871

34,692

attorneys of Micron Technology, Inc. as its attorneys with full power of substitution to prosecute this application and to transact all business in the Patent and Trademark Office in connection therewith.

The Assignee certifies that the above-identified assignment has been reviewed and to the best of the Assignee's knowledge and belief, title is in the assignee.

Please direct all correspondence regarding this application to the following:

Thomas J. D'Amico DICKSTEIN SHAPIRO MORIN & OSHINSKY LLP 2101 L Street NW Washington, DC 20037-1526 Telephone: (202) 785-9700 Fax: (202) 887-0689

Respectfully submitted,

MICRON TECHNOLOGY, INC.

Michael L. Lynch Chief Patent Counsel Registration No. 30,871

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE DECLARATION FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am an original, first and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled:

#### A REVERSE METAL PROCESS FOR CREATING A METAL SILICIDE TRANSISTOR GATE STRUCTURE

the specification of which is attached hereto.

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by an amendment, if any, specifically referred to in this oath or declaration.

I acknowledge the duty to disclose all information known to me which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56.

I hereby claim foreign priority benefits under Title 35, United States Code § 119/365 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

	Prior Foreign Application(s)			Priority Not Claimed
		4		
(Number)	(Country)	(F	iling Date)	
(Number)	 (Country)	(I	Filing Date)	_ 🗆
(Number)	 (Country)		Filing Date)	_ □

I hereby claim the benefit under Title 35, United States Code, § 120/365 of any United States and PCT international application(s) listed below and, insofar as

the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code,

§ 112, I acknowledge the duty to disclose all information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56(a) which became available between the filing date of the prior application and the national or PCT international filing date of this application:

(Application No.)	(Filing Date)	(Status) (patented, pending, abandoned)
(Application No.)	(Filing Date)	(Status) (patented, pending, abandoned)
(Application No.)	(Filing Date)	(Status) (patented, pending, abandoned)

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Please address all correspondence to Thomas J. D'Amico of **Dickstein** Shapiro Morin & Oshinsky LLP located at 2101 L Street NW, Washington, DC 20037-1526. Telephone calls should be made to (202) 785-9700.

Full name of first inventor: Werner Juengling

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# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE DECLARATION FOR PATENT APPLICATION

Signature Page for Second Inventor

Full name of second inventor: Richard H. Lane

Inventor's signature:

Date: 8/27/02

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Boise, Idaho US

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